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UV nanophotodetectors: A case study of individual Au-modified ZnO nanowires

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Abstract

In this work, ultraviolet (UV) nanophotodetectors based on individual gold-functionalized ZnO nanowires (Au/ZnO NWs) with different diameters and with different Au content were fabricated using a focused ion beam/scanning electron microscopy (FIB/SEM) system. The influence of the Au content, the diameter of the NWs, the applied bias voltage, the temperature and the relative humidity during operation on the UV sensing properties was investigated in detail. The necessity of a higher Au nanoparticles (NPs) coverage of individual Au/ZnO NWs in order to obtain higher UV response is demonstrated for the first time. A high UV response (I_{UV}/I_{dark}) of 21 for an individual Au/ZnO NW (with ~ 6.4% Au NPs coverage) was obtained, which is by a factor of 17 higher compared to unmodified ZnO NWs. The investigation regarding the NW diameter confirmed that thinner NWs are more suitable for UV sensing applications due to the greater influence of surface phenomena on electrical properties. Most importantly, the elaborated nanophotodetectors in this work, based on individual Au/ZnO NWs, show an extreme low influence caused by water vapors, i.e. relative humidity on UV response, which is critical for practical applications of high performance UV photodetectors in normal ambient conditions. Our experimental results demonstrate clearly that the *n*-type Au/ZnO NWs with enhanced optoelectronic properties are highly promising building nano-blocks for near future nano-optoelectronic devices and possible for biosensing applications.

1. Introduction

One-dimensional (1-D) ZnO nanostructures, such as nanowires, nanobelts, nanotubes and nanorods are ideal for building blocks for high-performance electronic, optoelectronic and sensing devices for environmental applications [1-9]. In the case of sensing devices (e.g. UV photodetectors and gas sensors) the high influence of surface phenomena, such as

adsorption/desorption of gaseous species on the electrical transport through a restricted conduction channel of 1-D nanostructures paves the way to fabricate highly sensitive UV photodetectors and gas sensors based on individual nanostructures [3, 7, 8, 10-15]. The main advantage of UV photodetectors based on individual ZnO NWs is the high internal gain, which is attributed to the presence of oxygen-related hole-trap states at the NW surface which prevents charge-carrier recombination through prolongation of the photo-carrier lifetime [16].

Different methods were reported in order to considerably enhance the UV sensing properties of individual ZnO NWs, such as doping [11], surface functionalization with noble metals [3], formation of individual Schottky contacts at one end of the NW [6], as well as functionalization with other metal oxide NPs [13], and the utilization of the piezo-phototronic effect [17]. For example, Hu *et al.* fabricated UV photodetectors based on a ZnS/ZnO biaxial nanobelt with high spectral selectivity and wide-range photoresponse in the UV-A band [18]. Lao *et al.* demonstrated that the UV response of individual ZnO nanobelts can be enhanced by almost 5 orders of magnitude by surface functionalizing with a polymer that has a high UV absorption ability [19]. While the UV sensing properties of photodetectors based on Au-modified ZnO micro- and nanostructures have been reported many works [20, 21], only the several results were reported based on individual Au-modified ZnO structures [3, 22]. For example, Liu *et al.* fabricated the UV photodetectors based on an individual ZnO NW with and without Au NPs and observed that surface-functionalization with Au NPs can drastically reduce the response time of ZnO nanowire photodetectors [3].

However, the interdependence of such important parameters as surface coverage with Au NPs and the diameter of the ZnO NW, relative humidity, applied bias and operation temperature were not investigated and reported. In this work, we integrated individual Au-modified ZnO NWs with different Au content and different diameters using a dual beam FIB/SEM system. The Au/ZnO NWs were synthesized in a one-step electrochemical deposition [23]. Besides the report

about the influence of the already enumerated factors, i.e. diameter, relative humidity, applied bias voltage and temperature for a single Au/ZnO NWs based device, the corresponding physical model and the mechanism of detection are tentatively proposed and discussed.

2. Experimental part

The Au/ZnO NW arrays were grown on glass sheet substrates coated with polycrystalline F-doped SnO₂ (FTO) having a resistance of 10 Ω/\square (used as a working electrode) by electrochemical deposition in a classical three-electrode electrochemical cell [11, 24]. The growth solution contained 0.2 mM ZnCl₂, 0.1 M KCl as supporting electrolyte and was subjected to continuous bubbling of oxygen in a bath solution [24, 25]. For variation of Au NPs content on the surface of ZnO NWs, different concentrations of HAuCl₄ (Sigma-Aldrich, >99.9%) were utilized (from 0.3 to 2.0 μ M). Upon deposition, the substrate was rotated at a constant speed of $\omega = 300$ rotations/min (rpm) [11, 24]. More details on the electrochemical deposition of doped ZnO NWs are presented in previous works [11, 24, 26]. The detailed morphological, structural, chemical and optical properties of Au/ZnO NW arrays were performed in the previous work [23] and indicated that Au ions are not incorporated in the ZnO matrix (i.e. no doping was observed or proved) but Au agglomerations are deposited on the surface of the ZnO NWs in the form of nanoclusters with a diameter in the range of 20 – 50 nm [23]. In other words, the growth and surface functionalization of ZnO NWs with Au nanoparticles is performed with the same electrochemical deposition process, which is an important advantage because it allows to cut down additional technological steps for post-growth surface functionalization [23].

The nanophotodetectors based on individual ZnO:Au NWs were fabricated using the method developed by Lupan *et al.* in a dual beam FIB/SEM scientific instrument [11, 23, 27, 28]. The UV sensing measurements were performed at room temperature (RT, ~ 25 °C) in normal

ambient air (relative humidity, RH \sim 20%). The UV light irradiance ($\lambda = 365$ nm) was set to ~ 1 mW/cm².

3. Results and discussions

3.1. Nanophotodetectors based on an individual Au/ZnO NW. Influence of Au NPs coverage

A typical SEM image of a nanophotodetectors fabricated using an individual Au/ZnO nanowire is presented in **Figure 1a**. The individual Au/ZnO NW, which is placed on SiO₂/Si substrate, is connected to Au/Cr electrodes using two Pt contacts. The current – voltage (I – V) characteristics of individual ZnO NWs with different Au NPs coverage (determined from SEM images of the devices and calculated by $(S_{NP} \cdot 100\%)/S_{NW}$, where S_{NP} is the Schottky contact area formed by Au NPs (πr^2 , where r is the Au NPs radius) and S_{NW} is the surface of the ZnO NWs ($2\pi r h$, where r and h are the radius and length of the NW) and with a 120 ± 10 nm diameter is presented in **Figure 1b**. The I – V measurements clearly show a resistance decrease of the devices with higher Au coverage. This can be attributed to the formation of the larger Schottky contact area, and respectively to the more narrowed conduction channel [3, 20, 29].

Figure 2a shows the room temperature UV photoresponse for individual Au/ZnO NWs with different Au NP coverage (determined from SEM images of the devices and calculated by $(S_{NP} \cdot 100\%)/S_{NW}$, where S_{NP} is the Schottky contact area formed by AuNPs (πr^2 , where r is the Au NPs radius) and S_{NW} is the surface of the ZnO NWs ($2\pi r L_{NW}$, where r_{NW} and L_{NW} are the radius and length of the NW)). The measurements were performed under 2 V bias voltage applied to the individual Au/ZnO NW. The SEM images of the nanodevices are shown in our previous work [23]. The content of Au NPs was mainly varied using different concentrations of HAuCl₄ in the electrolyte solution. From a previous work it was observed that by increasing the HAuCl₄ from 0.3 to 2.0 μ M, the concentration of Au NPs on the surface of the Au/ZnO NW arrays increased

[23]. However, in the Au/ZnO NW arrays grown using the same content of HAuCl₄ (for example 0.9 μ M), the Au/ZnO NW with a large variation of Au NPs on the surface can be found (even without Au NPs) [23]. Therefore, the number of Au NPs on the integrated individual Au/ZnO NW depends more on the chosen NW for integration, than on the HAuCl₄ content used for growth of these NWs. This is the reason why the UV response was plotted against the Au NPs coverage and not against the HAuCl₄ concentration used for growth of Au/ZnO NWs.

The UV response for Au NPs coverage of 0, ~ 1.2 , ~ 1.5 , ~ 3.5 and ~ 6.4 % is ~ 1.2 , ~ 2.75 , ~ 5 , ~ 9 and ~ 21 , respectively. As can be observed, the UV response increases with Au NPs coverage. Because the diameter of all NWs is about 120 ± 10 nm, the surface of the formed Schottky contacts at the Au/ZnO interface plays an important role for the determination of the device parameters [4, 20]. Thus, by increasing the surface of the Schottky contact, the higher influence of surface phenomena on the charge transport of an individual Au/ZnO NW can be achieved [30, 31].

Figure 2b shows the dynamic response to UV light of Au/ZnO NWs without Au NPs on the surface and with $\sim 1.2\%$ and $\sim 6.4\%$ Au NPs coverage. The rise and decay time constants of the photocurrent are determined through a bi-exponential fit respectively from the corresponding time-resolved measurements, as was reported previously [32]:

$$I(t) = I_{dark} + A_1 \left(1 - e^{-\frac{t}{\tau_{r1}}} \right) + A_2 \left(1 - e^{-\frac{t}{\tau_{r2}}} \right) \quad (1)$$

$$I(t) = I_{dark} + A_3 e^{-\frac{t}{\tau_{d1}}} + A_4 e^{-\frac{t}{\tau_{d2}}} \quad (2)$$

where A_1 , A_2 , A_3 and A_4 are positive constants. τ_{r1} , τ_{r2} and τ_{d1} , τ_{d2} are time constants for rising and decaying of the photocurrent, respectively. The results of the curve fittings are presented in **Figure 2c**. τ_{r1} and τ_{d1} are correlated to the rapid concentration change of the charge carriers when the UV light is switched on/off [33, 34]. τ_{r2} and τ_{d2} dependent of trapped carriers and their release due to

vacancies of oxygen defects in the thin film, as well as photodesorption/adsorption of oxygen molecules, which are in comparison much slower processes [33-35]. From **Figure 2c** it can be observed that by an increase in Au NP coverage of individual Au/ZnO NWs, the time constants of rising and decaying photocurrents are considerably decreased. This is more observable from **Figure S1a**, where the normalized UV response of Au/ZnO NWs from **Figure 2b** is presented. In the case of individual NWs without Au NPs and ~ 1.2% coverage a relatively low signal to noise ratio (SNR) can be observed. According to IUPAC definition, the signal is considered to be true if the $SNR > 3$ [36]. The SNR was defined as $|I_{UV} - I_{dark}|/\sigma$, where σ is the standard deviation of the current before illumination with UV light. The SNR for an individual Au/ZnO NW without Au NPs, with ~ 1.2 and ~ 6.4 % coverage is 11.49, 7.28 and 6.77, respectively, confirming that the signal is true.

The improved UV sensing properties of individual Au/ZnO NWs compared to a ZnO NW can be explained as follows. The UV sensing performances of micro- and nanostructures of metal oxides depend on electron – hole (e^-h^+) pairs generation and surface processes, such as adsorption/photodesorption of oxygen molecules [15, 37, 38]. In the dark, oxygen molecules (O_2) are adsorbed on the surface of the ZnO NW by capturing free electrons ($O_2 + e^- \rightarrow O_2^-$) [3, 39, 40]. In result, a surface electron depletion region (L_{dark}) is formed with a higher resistivity compared to the conduction channel (d_{dark} , see **Figure 2d**). In this case, the electrical conductance of the ZnO NW (G) is given by [41]:

$$G = |q|n_0\mu \frac{\pi[r_{NW} - L_{dark}]^2}{L_{NW}} \quad (3)$$

where q is the electron charge, n_0 is the concentration of free electrons and μ is the electron mobility.

Under UV illumination, e^-h^+ pairs are photogenerated [11]. While the e^- increases the photocurrent through the conduction channel of the NW, the h^+ migrates to the ZnO surface and

discharges O_2^- by surface electron-hole recombination ($h^+ + O_2^- \rightarrow O_2$), which leads to the narrowing of the surface electron depletion region (L_{UV}) and a widening of the conduction channel (d_{UV} , see **Figure 2f**) [11, 16]. The photoresponse in a steady state (ΔG_{ph} , when recombination and generation rates (g) are equal) is given by [41]:

$$\Delta G_{ph} \propto \Delta n = \Delta p = \frac{g}{1/\tau_{bulk} + 1/\tau_{surf}} \quad (4)$$

where Δn and Δp are the excess numbers of n and p carriers, and τ_{bulk} and τ_{surf} are the lifetimes of the photocarriers recombined in the bulk and at the surface.

In the case of Au/ZnO NWs, the presence of Au NPs on the surface leads to a formation of Schottky barriers at the Au/ZnO NW interface due to a higher work function of Au ($\phi_{Au} = 5.1$ eV) compared to those of ZnO ($\phi_{ZnO} = 4.1$ eV) (see **Figure 2e**) [3, 42]. This results in a much more narrowed conduction channel of the Au/ZnO NW, and a lower dark current, which was observed in **Figure 1b** [3, 11, 16]. Under UV illumination, the photogenerated holes will migrate to the Au NPs due to the interactive Coulomb force [3]. Some of the holes are trapped at the Au-ZnO interface and some of the holes pass through the Schottky barrier at the interface, where the electron-hole recombination will induce a reduction of the Schottky barrier and a narrowing of the electron depletion region, respectively (**Figure 2g**) [3]. Also, the presence of Au NPs can improve the light absorption efficiency by particle-induced light scattering, i.e. increasing the number of photogenerated e^-h^+ pairs [43], as well as increase the lifetime of photogenerated carriers and therefore the photoresponse by the increasing in the efficiency of charge carrier separation (see eq. (4)) [41, 44]. Therefore, the particle-induced scattering and Au/ZnO Schottky barriers can be responsible for the great enhancement of UV sensing properties of an individual Au/ZnO NW-based nanophotodetector [3].

3.2. Influence of the nanowire diameter on sensing performances

The sensing mechanism of individual ZnO micro- and nanostructures is primarily surface related, therefore surface states, oxygen adsorption quantities and the diameter play important roles on the UV sensitivity [3, 45], the influence of the latter for an individual Au/ZnO NW was also investigated. **Figure 3a** shows the room temperature UV response of a Au/ZnO NW (with ~ 6.4% coverage) versus the diameter. The measurements were performed with 2 V bias voltage. The UV response for Au/ZnO NWs with individual diameters of 120, 150, 190, 220 and 240 nm is ~ 21, ~ 12, ~ 5.5, ~ 3.5 and ~ 3, respectively. The results show a considerable decrease in the UV response with the NW diameter enlargement from 120 to 240 nm. The dynamic responses for NWs with 120, 190 and 240 nm are presented in **Figure 3b**. The calculated time constants for rising and decaying of the photocurrent in dependence of the NW diameter are presented in **Figure 3c**. As can be observed, the recovery of the photocurrent is found to be strongly related to the diameter of NWs, which is more observable from **Figure 3d**.

The size-dependent UV sensing properties of individual nanostructures were observed by several authors [46-50]. The decrease in response by a widening of the diameter of the NW can be explained based on a reduced influence of surface phenomena on the conductive channel of the NW (see **Figure 3e**). Chen *et al.* demonstrated that the recovery of the photocurrent for an individual ZnO NW is found to be strongly related to the diameter of NWs, indicating that the photocarrier relaxation behavior is dominated by surface band bending [48]. It can explain the observed data from **Figure 3c**, i.e. dependence of the time constants for rising and decaying photocurrents.

3.3. Influence of the operating temperature and the applied bias voltage on sensing performances

Next, the influence of the operating temperature and the applied bias on the UV sensing properties is investigated. **Figure 4a** shows the current – voltage (*I-V*) characteristic of individual

Au/ZnO NWs (with $\sim 6.4\%$ coverage) with a diameter of 120 nm at different operating temperatures (25, 70, 100 and 150 °C). A typical semiconductor I - V characteristic, i.e. increasing of the current value at higher temperatures due to thermal activation of the charge carriers [2, 8], is found. The dependence of the UV response on the applied bias and operating temperature is presented in **Figure 4b**. It is observed that the highest UV response is obtained at 2 V (~ 21), while a further increase in bias voltage to 4 V and 6 V leads to a response decrease to 5 and 1.1, respectively. At an applied bias voltage of 1 V the UV response is much lower, ~ 3.5 . Increasing the operating temperature reduces the UV response (see **Figure 4b**). The UV response at 25, 40, 70, 100 and 150 °C is ~ 21 , ~ 12 , ~ 8.9 , ~ 8.7 and ~ 8.4 , respectively. The dynamic response of individual Au/ZnO NWs with a diameter of 120 nm at different applied bias voltages and different operating temperatures (25, 70 and 150 °C) is presented in **Figure 4c** and **4d**, respectively.

The reduction in the UV sensing performance at elevated operating temperatures can be explained mainly by the higher dark current due to an enhancement in tunneling currents [51] and the increased probability of recombination of photogenerated $e^- - h^+$ pairs [52]. The decreasing in the UV response by increasing applied bias voltages can be explained based on the well-known self-heating effect [53, 54]. Therefore, the higher the applied bias, the more heat will be generated by Joule dissipation [41]. Strelcov *et al.* assumed that the temperature of the self-heated suspended NW has a linear gradient from highest temperature in the center to the ambient temperature at the electrical leads and that the Joule power, generated in such a NW, is dissipated via three channels: heat transfer to the ambient gas, to the metal contacts and via radiation losses [54]. However, in our case the Au/ZnO NWs are placed on SiO₂ (300 nm)/Si substrates, and a part of the temperature is dissipated through this substrate.

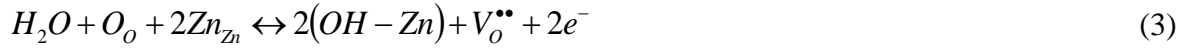
As a future perspective, the self-heating effect by Joule dissipation could be improved using suspended NWs.

3.4. Influence of the relative humidity on sensing performances

Because the UV sensing properties of UV photodetectors, such as the UV response and the time constants (response/recovery), are dominated by surface phenomena/processes involving adsorption/desorption of oxygen species, other chemical species in the environment reduce or increase the response/recovery time [55]. In particular, water molecules are present in high quantities in the environment and can affect the sensing performances of ZnO micro- and nanostructures. It remains a serious limitation for practical photosensing applications [35, 55, 56]. Therefore, without surface passivation the effect of water vapors is hard to avoid. In this context, the humidity influence on UV sensing properties of individual ZnO nanostructures was less reported [57].

Our previous measurements were performed at a normal ambient RH of $\sim 20\%$ and we also performed UV sensing measurements at higher values of RH of $\sim 60\%$ and $\sim 80\%$ at room temperature. Results of an individual Au/ZnO NW with a diameter of 190 nm are presented in **Figure 5a**. The data are presented using the measured current, in order to better demonstrate the influence of the modified RH on the dark current. Neither essential changes in dark currents nor in the value of the UV response were visible with the RH value. The calculated time constants for the rising and decaying photocurrent in dependence of the RH are presented in **Figure 5b**. The time constants for the rising photocurrent show no essential changes, while in the case of the time constants for the decaying photocurrent a slight decrease in the values can be observed. The dynamic response to multiple pulses at 80% RH is presented in **Figure 5c**, in order to demonstrate the good repeatability even at high values of RH. **Figure 5d** shows the UV response at different values of RH (20, 60 and 90%) for an individual Au/ZnO NW with diameter of 190 nm and with a different Au NPs coverage on the surface. The results clearly demonstrate that a lower coverage with Au NPs leads to a higher dependence of the UV response on the RH.

The low impact of water vapors on the UV sensing properties of an individual Au/ZnO NW can be explained as follows. In presence of water vapors the current level in the dark is slightly increased and under illumination significantly decreased [56]. These current modifications are attributed to the adsorption of water molecules (H_2O) on the surface of ZnO by generation of free electrons [35, 58]:



where $V_o^{\bullet\bullet}$ is the vacancy created at an oxygen site, O_o is the oxygen atom from the lattice and Zn_{zn} is the zinc atom from the lattice. Therefore, by increasing the concentration of water molecules, more adsorption sites on the ZnO NW surface are occupied by hydroxyl groups and increase the value of the dark current by narrowing the width of the electron depletion region [35, 58, 59]. This reduces the lifetime of photogenerated carriers leading to a lower photocurrent [35, 58, 59]. More details about the mechanism are presented in our previous work [35]. However, in our case the lack of changes in the dark- and photocurrent may indicate that Au NPs act as hydroxyl adsorbers on the surface of NPs, thereby providing an oxygen adsorption site for surface reactions in a humid atmosphere [60]. The same effect was observed for NiO-doped SnO_2 [61], Sb-doped SnO_2 [62], CuO-loaded SnO_2 hollow spheres [63], Al-doped SnO_2 NPs [60] and Fe_2O_3 -functionalized ZnO tetrapods [13].

Figure 6 shows the schematic model of hydroxyl and oxygen co-adsorption on the surface of ZnO and Au/ZnO NW. In the presence of humidity the hydroxyl groups are adsorbed on the surface of the ZnO NW resulting in width changes of the conduction channel L_{air} (see **Figure 6a,b**). By the increase in concentration of water vapors, the adsorption of oxygen species is highly decreased due to hydroxyl poisoning, which was confirmed by other investigations [60, 61], and extends the width of the conduction channel (L_{air+RH} , see **Figure 6a,b**). Thus, less photogenerated holes under UV illumination will migrate to the ZnO surface to discharge O_2^- by surface electron-

hole recombination, leading to the lowering in modulation of the conduction channel and respectively to lowering in the UV response (see **Figure 6c**) [11, 16].

In the case of a Au/ZnO NW (see **Figure 6d,e**), the hydroxyl groups are adsorbed mainly on the surface of Au NPs, maintaining the adsorption of O_2^- even at high water vapors concentration (in our case even at 80%). Thus, we believe that Au NPs act as hydroxyl absorbers by preferential capture [60, 61]. In result, the high modulation of the conduction channel under UV illumination is maintained and even increased (**Figure 6f**), as was already described.

4. Conclusions

In summary, the individual Au-functionalized ZnO NWs were successfully integrated into nanophotodetector devices using a dual beam FIB/SEM system. The electrodeposition of a high number of Au NPs on the ZnO NW surface leads to the formation of Schottky contacts which in turn improves the UV sensing performances. In particular, an UV response ($S = I_{UV}/I_{dark}$) of about 21 was obtained for Au/ZnO NWs, which is higher by a factor of 17 compared to unmodified ZnO NWs, demonstrating the high efficiency of Au NPs-surface functionalization of individual ZnO NWs. The investigation of the diameter influence on the UV response revealed that the higher UV response of thinner Au/ZnO NWs is based on the higher influence of adsorption/photodesorption of oxygen species on electrical properties. Other factors that can decrease the UV sensing properties of individual Au/ZnO NWs are higher temperatures and applied bias voltages (which can be also attributed to rise in temperature due to the self-heating effect). In this case the decrease in the UV sensing properties was attributed to the increased dark current due to an enhancement in tunneling currents and the increased probability of recombination of photogenerated $e^- - h^+$ pairs. A physical model for the sensing mechanism based on the band energy theory was proposed to show the origin of the improvement of the UV detection performance for the Au/ZnO nanowire

nanophotodetector. The main advantage of such individual Au/ZnO NWs is the lower influence of water vapors on the UV response, which is very important for practical applications.

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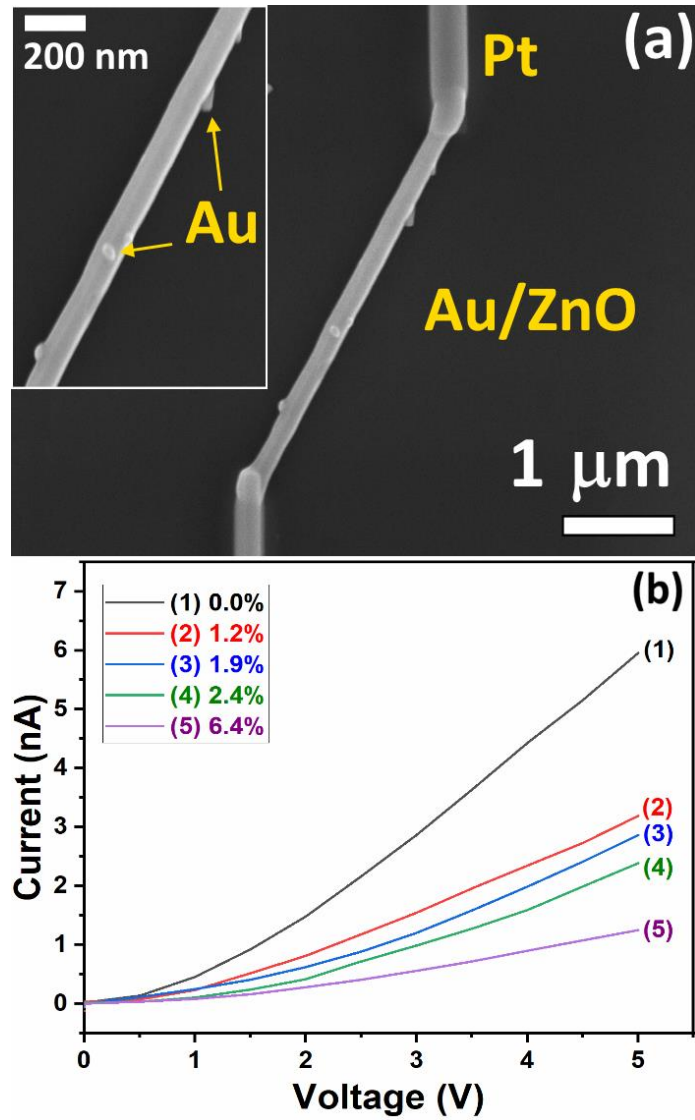


Figure 1. (a) SEM image of a nanophotodetector based on an individual Au/ZnO NW with a diameter of 150 nm. The inset presents a zoomed region with Au NPs attached on the surface of the NW. (b) Current – voltage (I – V) characteristics of individual Au/ZnO NWs with different Au NPs coverage.

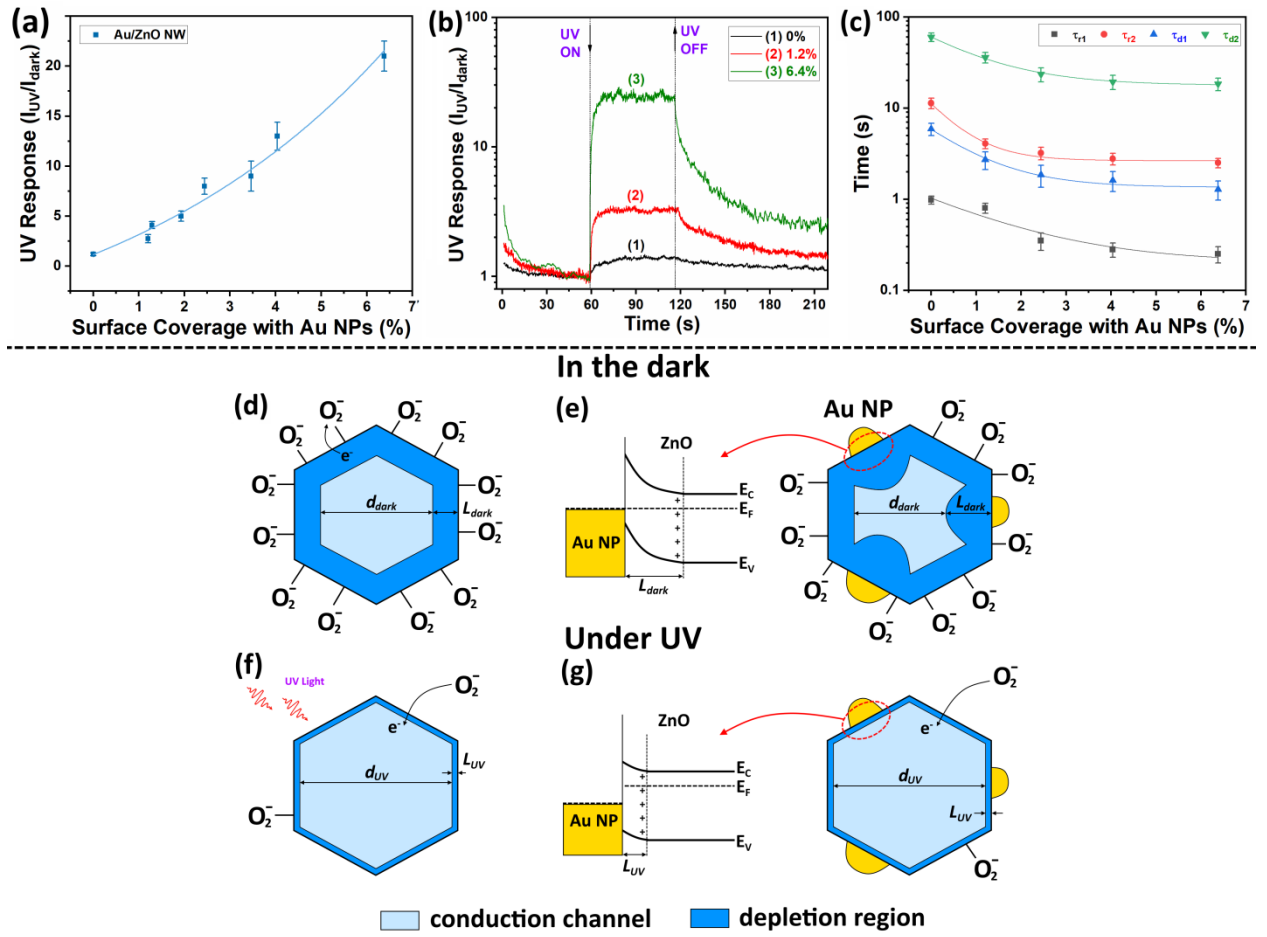


Figure 2. (a) Measured UV response of individual Au/ZnO NWs (with $D = 120$ nm) versus Au NPs coverage on the surface of NW. (b) Dynamic UV response of individual Au/ZnO NWs with different Au NPs coverage on the surface. (c) The calculated time constants of rising and decaying photocurrent for individual Au/ZnO NWs. The UV sensing mechanism of individual ZnO NW and Au/ZnO NW: ZnO NW in the dark (d) and under UV illumination (f); Au/ZnO NW in the dark (e) and under UV illumination (g).

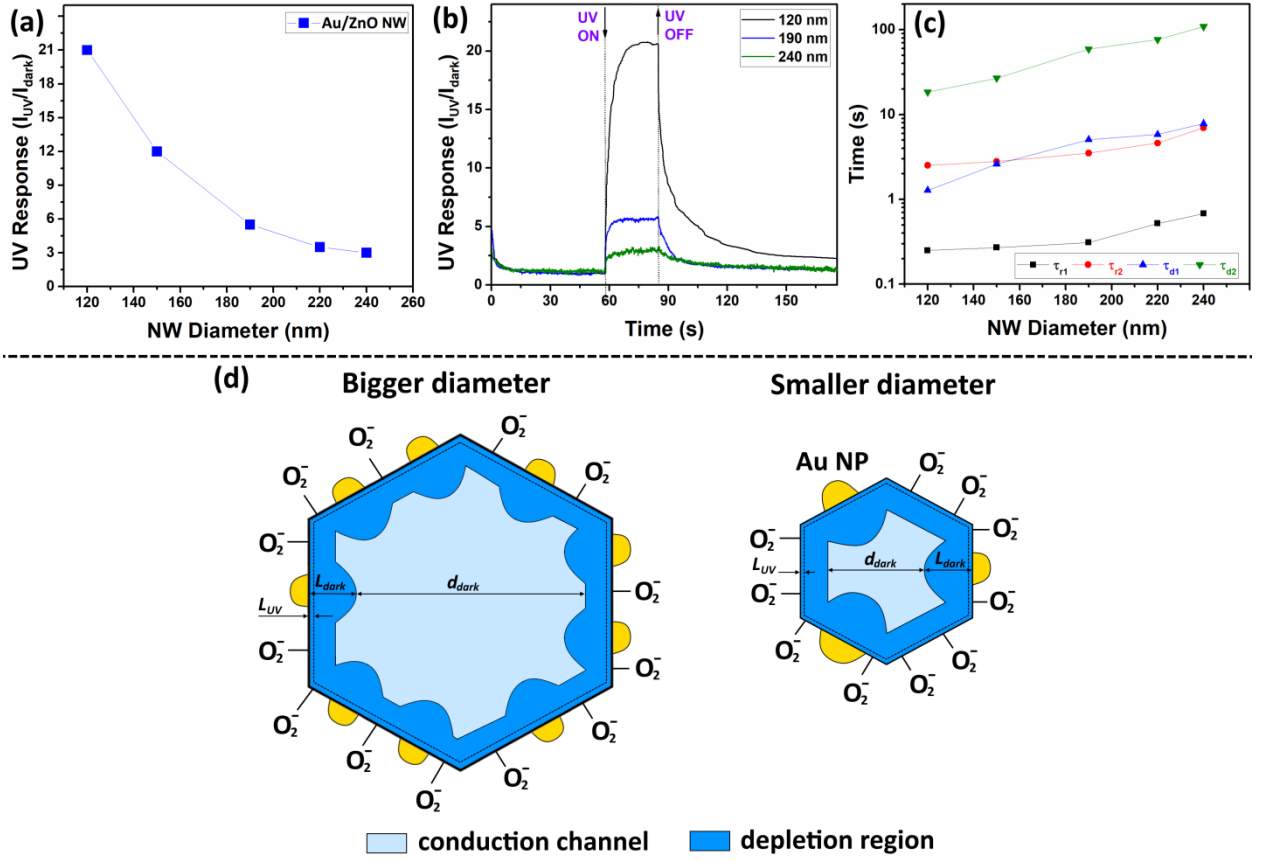


Figure 3. (a) UV response of individual Au/ZnO NWs versus diameter of the nanowire integrated in nanosensor. (b) Dynamic UV response of individual Au/ZnO NWs with different diameters. (c) The calculated time constants for rising and decaying photocurrent of individual Au/ZnO NWs with different diameters. (d) The UV sensing mechanism based on different diameter (bigger and smaller one) of an Au/ZnO NW used in nanosensors in cross-sectional view.

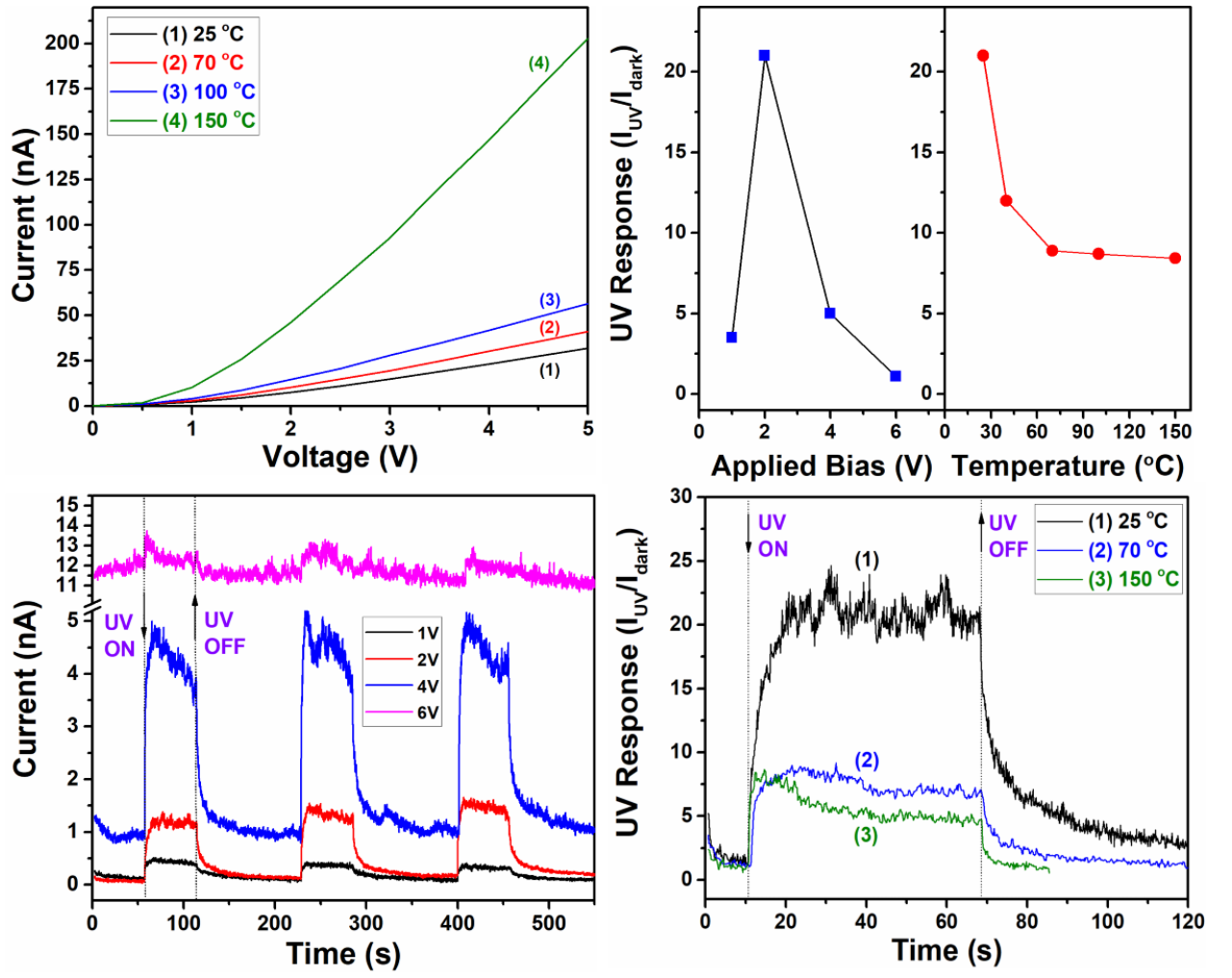


Figure 4. (a) Current – voltage characteristic of an Au/ZnO NW with diameter of 120 nm at different operating temperatures. (b) UV response versus applied bias voltage and operating temperature. Dynamic UV response at different (c) applied bias voltage and (d) operating temperatures.

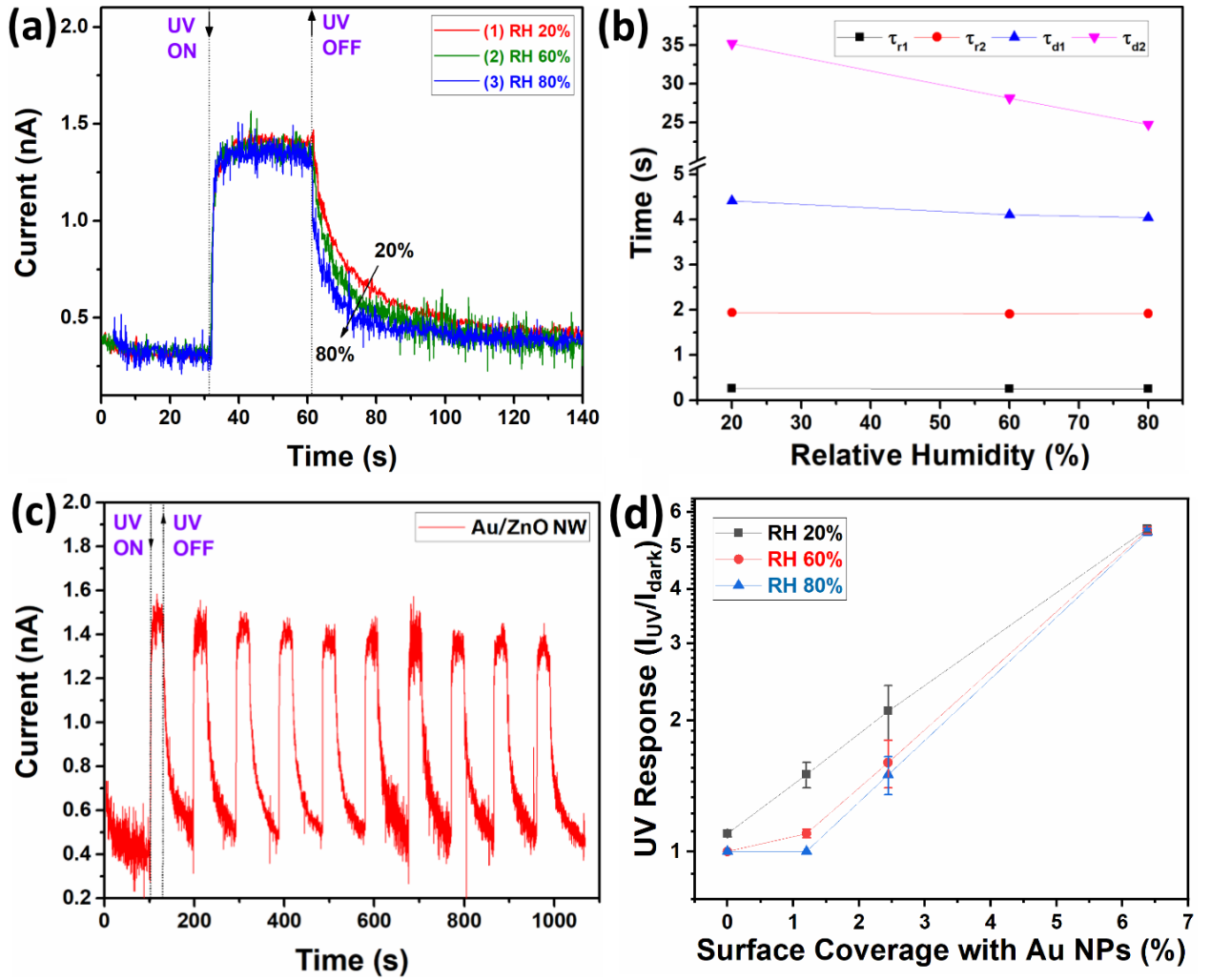


Figure 5. (a) Dynamic UV response of Au/ZnO NWs with diameter of 190 nm at different values of relative humidity. (b) The calculated time constants for rising and decaying photocurrent. (c) Dynamic response to multiple pulses at 80% RH. (d) UV response at different values of RH for individual Au/ZnO NWs with diameter of 190 nm and different content of Au NPs on the surface. (d) UV response at different values of RH (20, 60 and 90%) for individual Au/ZnO NW with diameter of 190 nm and with different Au NPs coverage on the surface.

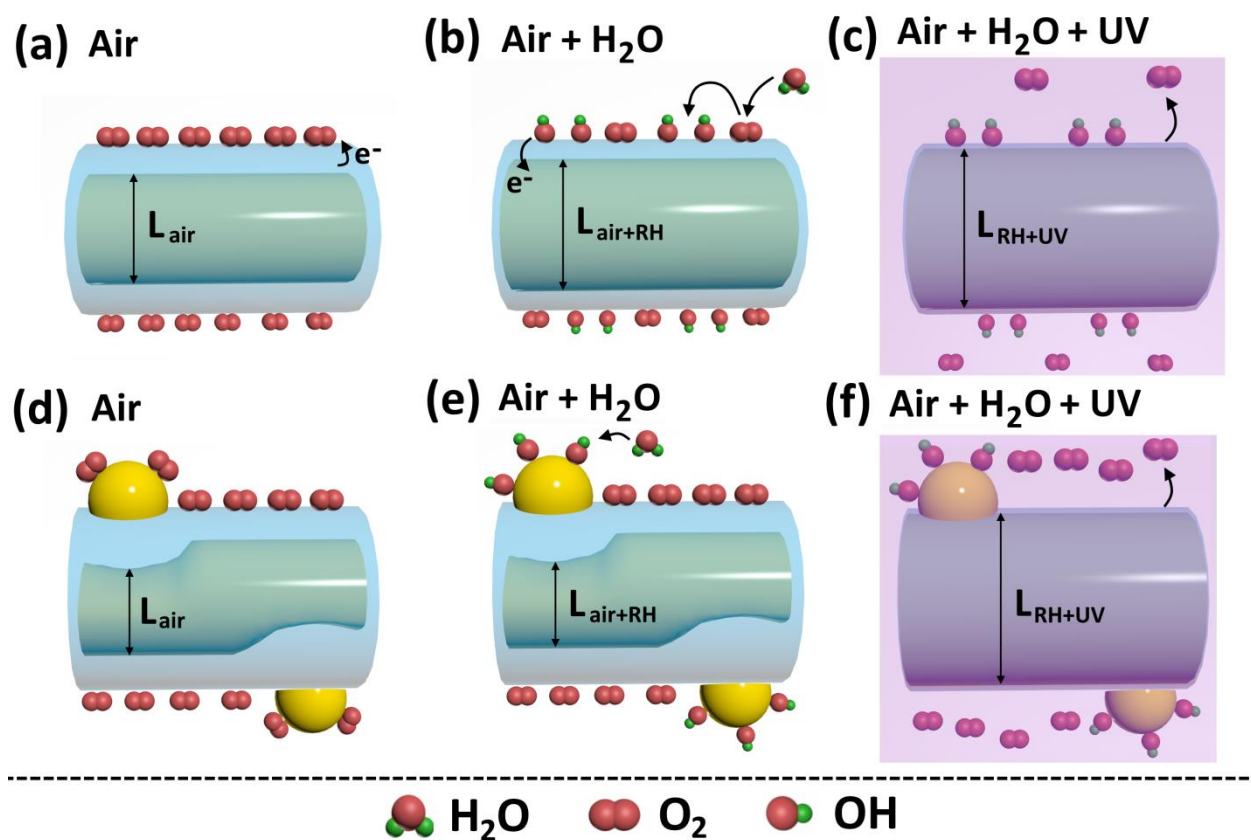


Figure 6. Schematic model of hydroxyl and oxygen molecules co-adsorption on the surface of: (a) ZnO NW and (b) Au/ZnO NW.

Supporting Information

for

UV nanophotodetectors: A case study of individual Au-modified ZnO nanowires

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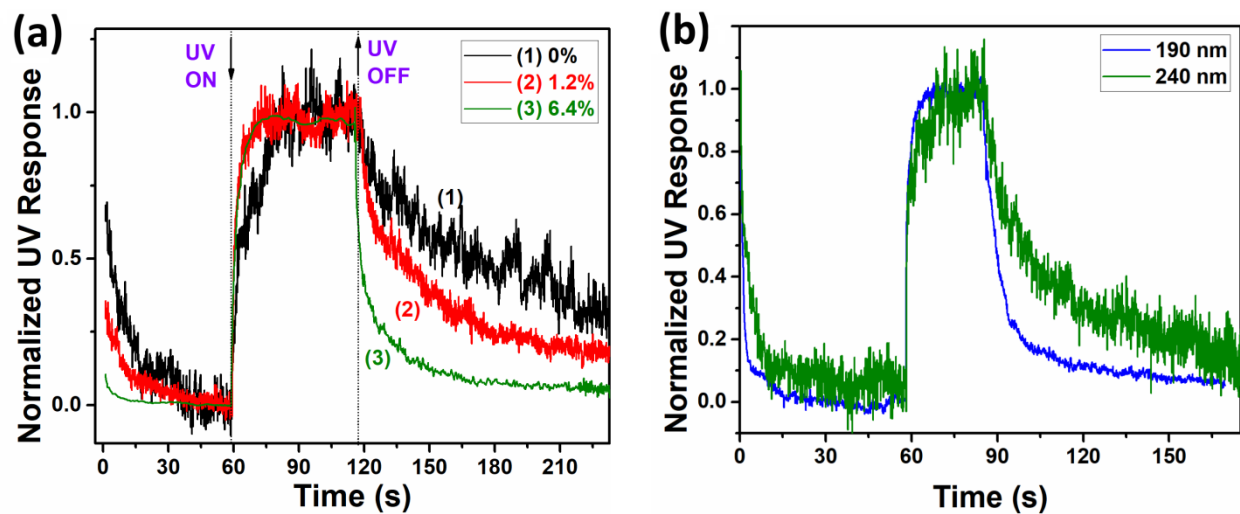


Figure S1. (a) Normalized UV response of individual Au/ZnO NWs with different content of Au NPs on the surface. (b) Normalized UV response of individual Au/ZnO NWs with diameter of 190 and 240 nm.